

**20V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26**
**Features**

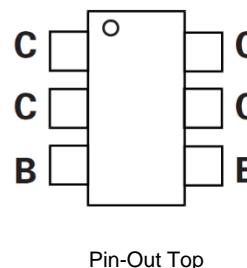
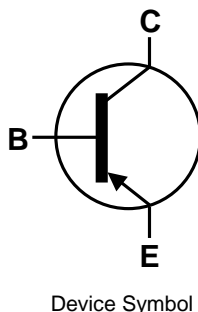
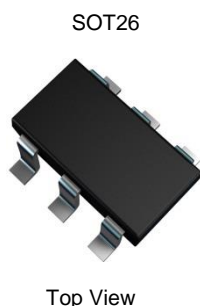
- $BV_{CEO} > -20V$
- $I_C = -2.5A$  Continuous Collector Current
- $I_{CM} = -6A$  Peak Pulse Current
- $R_{CE(sat)} = 96m\Omega$  for a Low Equivalent On-Resistance
- Low Saturation Voltage ( $-220mV$  max @ 1A)
- $h_{FE}$  Characterized up to  $-6A$  for High Current Gain Hold-Up
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.015 grams (Approximate)

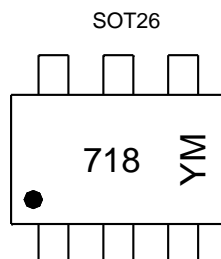
**Applications**

- DC-DC Converters
- Power Management Functions
- Power Switches
- Motor Control


**Ordering Information** (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT10P20DE6TA	718	7	8	3,000
ZXT10P20DE6TC	718	13	8	10,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**


718 = Product Type Marking Code  
 YM = Date Code Marking  
 Y or  $\bar{Y}$  = Year (ex: C = 2015)  
 M or  $\bar{M}$  = Month (ex: 9 = September)

**Date Code Key**

Year	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	C	D	E	F	G	H	I	J	K	L	M

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-20	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-20	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Base Current	I <sub>B</sub>	-500	mA
Continuous Collector Current	I <sub>C</sub>	-2.5	A
Peak Pulse Collector Current	I <sub>CM</sub>	-6	A

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

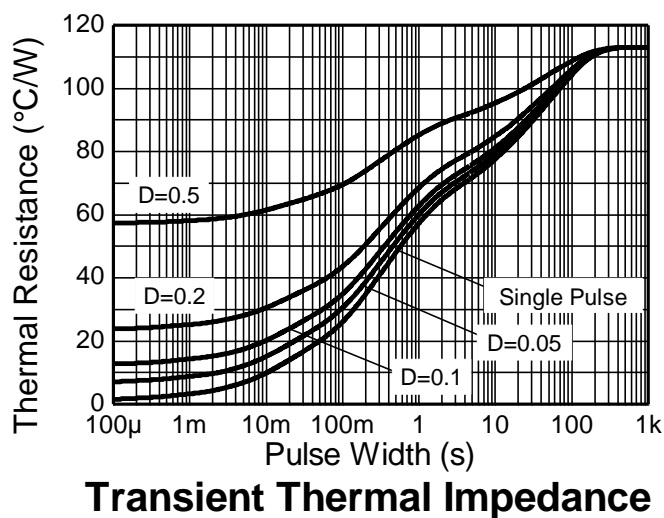
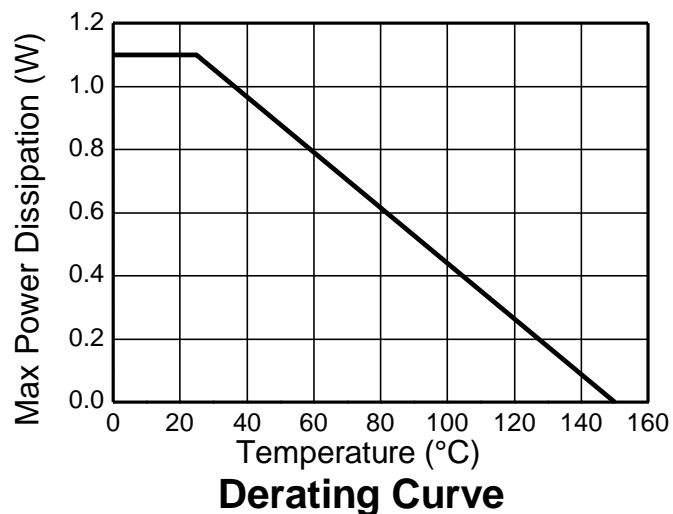
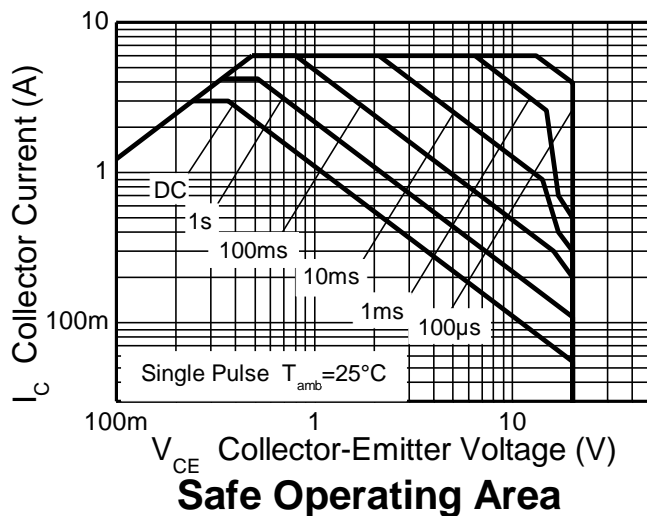
Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	1.1	W
Linear Derating Factor		8.8	
	P <sub>D</sub>	1.7	mW/°C
		13.6	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	113	°C/W
		73	
Thermal Resistance, Junction to Leads	R <sub>θJL</sub>	30.01	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  - Same as Note 5, except the device is measured at t ≤ 5secs.
  - Thermal resistance from junction to solder-point (at the end of the collector leads).
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

## Thermal Characteristics and Derating Information

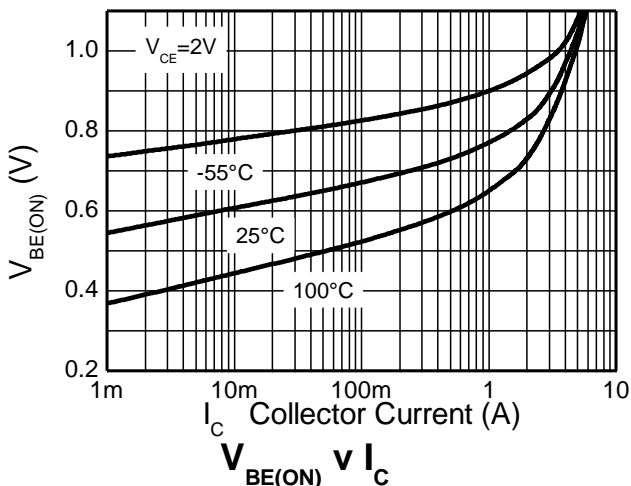
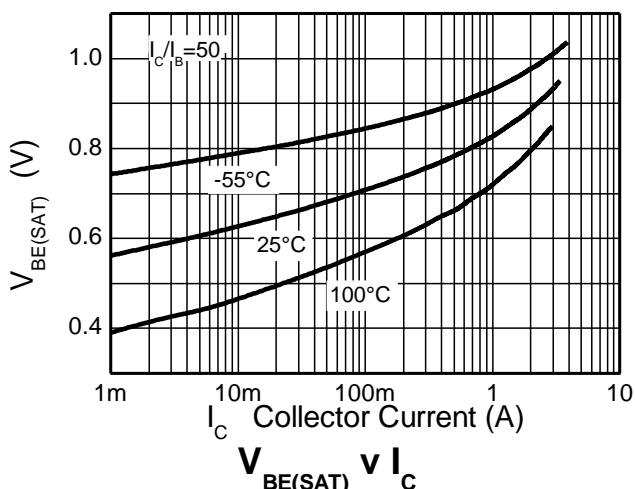
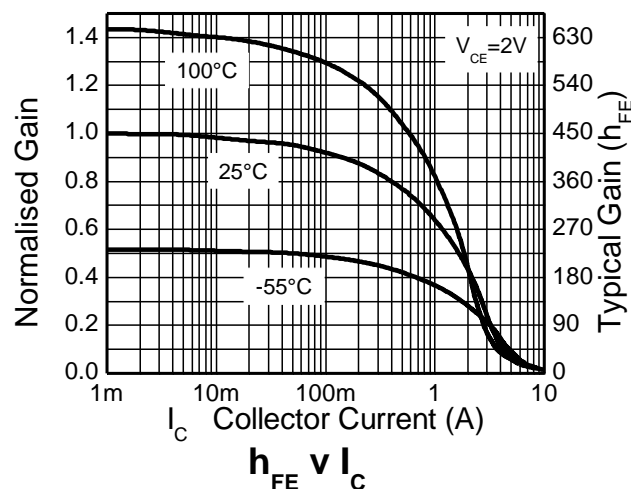
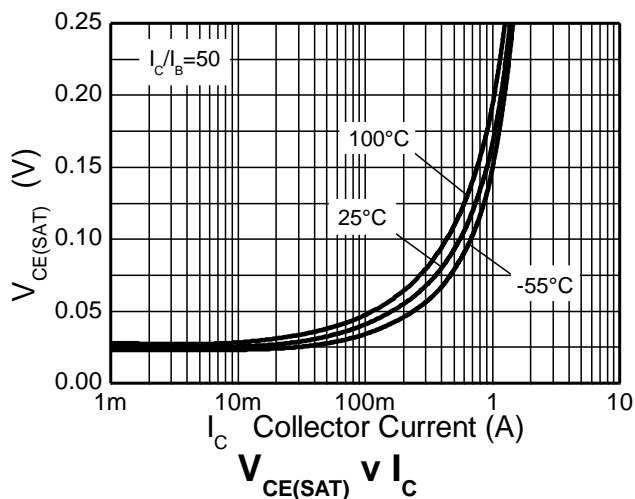
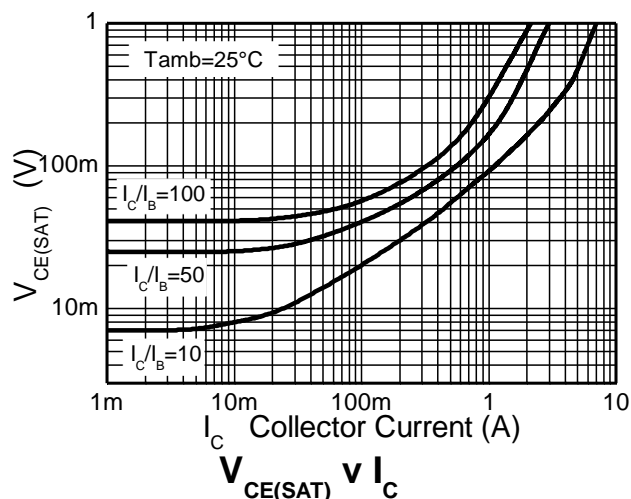


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-20	-65	—	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-20	-53	—	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.8	—	V	I <sub>E</sub> = -100μA
Collector-Base Cutoff Current	I <sub>CBO</sub>	—	<1	-100	nA	V <sub>CB</sub> = -15V
Emitter Cutoff Current	I <sub>EBO</sub>	—	<1	-100	nA	V <sub>EB</sub> = -5V
Collector-Emitter Cutoff Current	I <sub>CES</sub>	—	<1	-100	nA	V <sub>CES</sub> = -15V
<b>ON CHARACTERISTICS</b> (Note 9)						
DC Current Gain	h <sub>FE</sub>	300	475	—	—	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -2V
		300	450	—	—	I <sub>C</sub> = -0.1A, V <sub>CE</sub> = -2V
		150	230	—	—	I <sub>C</sub> = -2A, V <sub>CE</sub> = -2V
		15	30	—	—	I <sub>C</sub> = -6A, V <sub>CE</sub> = -2V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	-19	-30	mV	I <sub>C</sub> = -0.1A, I <sub>B</sub> = -10mA
		—	-170	-220		I <sub>C</sub> = -1A, I <sub>B</sub> = -20mA
		—	-190	-250		I <sub>C</sub> = -1.5A, I <sub>B</sub> = -50mA
		—	-240	-350		I <sub>C</sub> = -2.5A, I <sub>B</sub> = -150mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	—	-0.97	-1.05	V	I <sub>C</sub> = -2.5A, I <sub>B</sub> = -150mA
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>	—	-0.85	-0.95	V	I <sub>C</sub> = -2.5A, V <sub>CE</sub> = -2V
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Current Gain-Bandwidth Product	f <sub>T</sub>	150	180	—	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA, f = 100MHz
Output Capacitance	C <sub>obo</sub>	—	21	30	pF	V <sub>CB</sub> = -10V, f = 1MHz
Turn-On Time	t <sub>(on)</sub>	—	40	—	ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -1A
Turn-Off Time	t <sub>(off)</sub>	—	670	—	ns	I <sub>B1</sub> = -I <sub>B2</sub> = -20mA

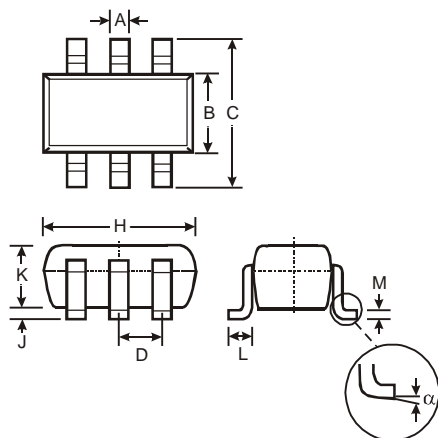
Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



## Package Outline Dimensions

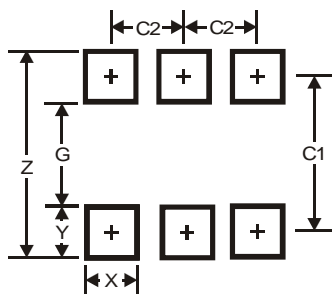
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
$\alpha$	0°	8°	—
All Dimensions in mm			

## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

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